CORRECTION

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Correction: Thermoelectric properties of Te-doped ternary CuAgSe compounds

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Correction for 'Thermoelectric properties of Te-doped ternary CuAgSe compounds' by P. F. Qiu *et al.*, *J. Mater. Chem. A*, 2015, DOI: 10.1039/c5ta06780d.

Fig. 4 of the above manuscript is incorrect and should be as shown in the figure below.

Fig. 4 (a) Temperature dependences of (a) C_{xx}/σ_{xx} and (b) C_{xy} for $\text{CuAgSe}_{1-y}\text{Te}_y$ ($y = 0, 0.05, 0.1$, and 0.15) samples; the dotted lines represent the data for the non-stoichiometric CuAgSe reported in ref. 14.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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